

Application No.: 09/745,527
Amendment dated October 17, 2003
Reply to Office Action of July 18, 2003

Docket No.: 8733.345.00-US

Amendments to the Drawings:

The attached sheet of drawings includes changes to Fig. 2. This sheet, which includes Figs. 1-2, replaces the original sheets including Figs. 1-2.

Attachment: Replacement Sheet
Annotated Sheet Showing Changes



Fig. 1 is a cross-sectional view of a semiconductor device. It shows a substrate 1 with a top layer 2. A series of rectangular blocks 14 are formed on the substrate. Above these blocks is a layer 10 containing circular features. A top layer 4 is on top of layer 10. A layer 8 is on top of layer 4. A layer 12 is on top of layer 8. A layer 6 is on the left side. A layer 20 is on the right side. Dimensions S and P are indicated at the bottom.